

Unraveling the Myths and Mysteries of Photon Avalanching Nanoparticles

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Abstract

Photon avalanching (PA) nanomaterials exhibit some of the most nonlinear optical phenomena reported for any material, allowing them to push the frontiers of applications ranging from super-resolution imaging and ultra-sensitive sensing to optical computing. But PA remains shrouded in mystery, with its underlying physics and limitations misunderstood. Photon avalanching is not, in fact, an avalanche of photons, at least not in the same way that snowballs beget more snowballing in an actual avalanche. In this focus article, we dispel these and other common myths surrounding PA in lanthanide-based nanoparticles and unravel the mysteries of this unique nonlinear optical effect. We hope that removing the misconceptions surrounding avalanching nanoparticles will inspire new interest and applications that harness the giant nonlinearity of PA across a broad range of scientific fields.

1. Introduction

When one thinks of photon avalanching in a material, one might envision a photon stimulating the emission of additional photons, which each go on to stimulate even more photons in an optical chain reaction (**Figure 1**, left). While this cartoon image may be useful for illustrating the general nonlinearity of PA, the aforementioned process more accurately describes amplified stimulated emission or lasing than photon avalanching (PA).^{1, 2} Confusingly, photon avalanching is not actually an avalanche of photons. Unlike a real avalanche, in which snow cascading down a mountain stimulates even more falling snow in a nonlinear chain reaction, the photons emitted by PA materials do not feed back into the production of more photons. Instead, PA is more of a feedback loop of excited ions begetting more excited ions, or absorption begetting more absorption (**Figure 1**, right).³

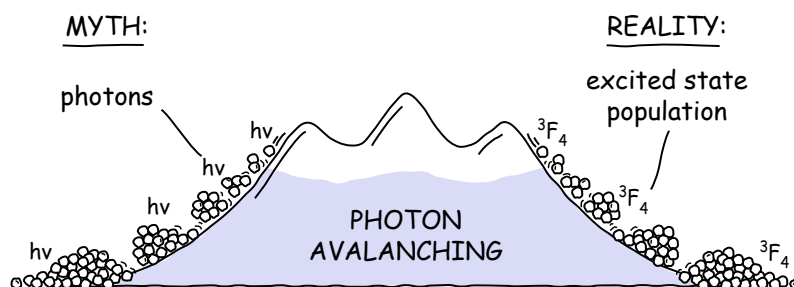


Figure 1. Photon avalanches are not avalanches of photons, but rather, avalanches in the population of excited ions (promoted by an avalanche of photon absorption).

Why do these misconceptions persist? For one, “excited state population avalanching” or “absorption avalanching” does not capture the imagination quite like an avalanche of photons does. PA may also be misunderstood because it is a relatively esoteric phenomenon that, until recently, was the subject of relatively little research activity outside a small community of scientists studying lanthanide-doped bulk crystals and other nonlinear optical materials.⁴ The recent observation of true PA in lanthanide (Ln^{3+})-doped nanoparticles has sparked newfound interest in PA, especially since these colloidal, solution-processable avalanching nanoparticles (ANPs) have demonstrated applications in super-resolution imaging (with <100 nm resolution and <1 Å localization accuracies),^{5, 6} nanoscale temperature⁷ and pressure sensing,⁸ and in optical memory⁹ and logic.¹⁰ It is possible that, in the excitement surrounding these groundbreaking applications and the giant nonlinearity of PA (sometimes exceeding that of a 100-photon process^{9, 11}), the fundamental processes and nuances that underly PA get

overlooked. While several recent and historical reviews have comprehensively discussed the mechanism and application of PA materials^{3, 12} and nanoparticles,^{4, 13, 14} there is a strong need to clarify frequently misunderstood yet essential concepts.

In this Focus Article, we dispel 13 common myths about PA nanomaterials and remove the shroud of mystery surrounding these uniquely nonlinear systems. In the process, we highlight the essential features of the PA mechanism and use them to explain the unique but sometimes contradictory behavior of PA materials. The case studies presented here will explore why PA may be simultaneously underappreciated as an optical phenomenon and also unlikely to live up to its more extreme hype due to nuances that may not be readily apparent. Ultimately, unraveling the enigma of PA nanomaterials will allow a broader range of scientists to fully exploit their potential and develop a wide range of applications that can leverage the extreme nonlinearity of these materials.

2. The Mysteries of ANPs

As provocative as their name is, the composition and behavior of PA materials remain an enigma to many scientists. Here, we first address some of the mysteries of ANPs before we explore myths about their behavior.

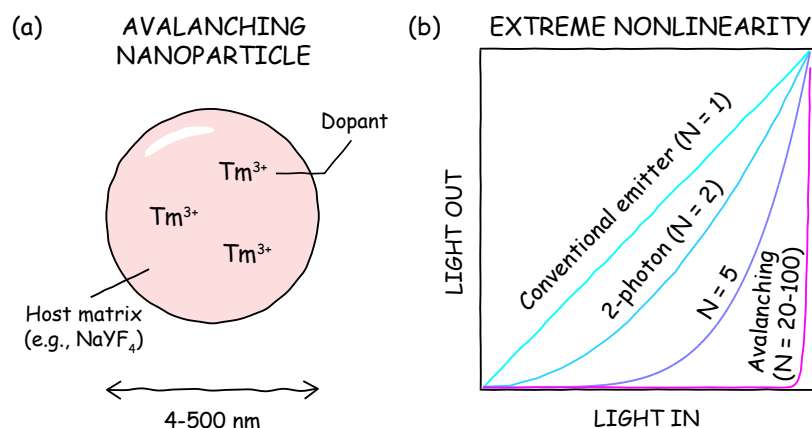


Figure 2. Avalanching nanoparticles. (a) Schematic of a lanthanide-doped photon avalanching nanoparticle. (b) Output light intensity vs input excitation intensity, showing on a linear scale the nonlinearity N of the emission from avalanching nanoparticles (20-100+) compared to conventional, 2-photon, and 5-photon emitters.

Mystery #1: What is a photon avalanching nanoparticle?

ANPs are nanocrystals – typically 5-100 nm in diameter and doped with Ln³⁺ ions (**Figure 2a**) – that upconvert low-energy photons to higher-energy ones with an extremely nonlinear optical response. ANPs harness a positive feedback loop of photophysical interactions between Ln³⁺ ions (e.g., energy transfer), bringing about a highly nonlinear optical response in which their emission intensity (I_{em}) scales with the power density (P_{ex}) of the excitation radiation as $I_{em} \sim P_{ex}^N$ (**Figure 2b**), where N signifies the order of the nonlinearity.¹⁵ While $N = 1$ for conventional fluorophores and $N = 2$ for two-photon emitters, the first experimentally confirmed ANPs, based on Tm³⁺:NaYF₄ nanocrystals, exhibited N as high as 31.⁵ This unprecedented nonlinearity, equivalent to a 31-photon process, made these ANPs some of the most nonlinear materials reported at the time, and the first single nanomaterials to exhibit PA. Later work revealed that ANPs doped with different combinations of lanthanide ions (e.g., Yb³⁺/Pr³⁺, with Tm,³⁺ Er³⁺, or Ho³⁺), strategically partitioned across heterostructures with multiple concentric shells,¹⁶ could achieve even higher nonlinearities of 41,¹⁷ 46,¹⁸ and even 60.¹⁹ Most recently, Tm³⁺- or Nd³⁺-doped ANPs with alternative host matrices (e.g., NaLuF₄,¹¹ KMgF₃,²⁰ KPb₂Cl₅)²¹ have been reported in some cases to exhibit step-like optical responses that imply nonlinearities greater than 100.^{9, 11}

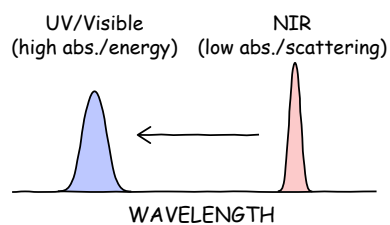
Mystery #2: Why is such high nonlinearity useful?

The high nonlinearity of ANPs has immense implications beyond the spectral conversion applications (**Figure 3a**) that are commonly associated with nonlinear optical materials.²² For $N = 30$, doubling P_{ex} theoretically increases the emission intensity by 2^{30} , or a billion times, though in actual experiments, the saturation of Tm³⁺: NaYF₄ ANPs resulted in “only” a 10⁴-fold increase.⁵ When $N = 100$, the same order of emission enhancement can be achieved with only a 10% increase in P_{ex} . Thus, the absorption of a small number of additional photons produces a disproportionate response of upconverted photons - a form of an avalanche.

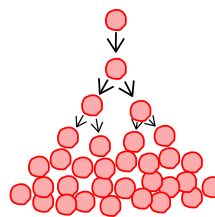
To understand why such nonlinearity is useful, we look towards other nonlinear systems. PA is a chain reaction in which excited ions beget excited ions, making it analogous to an autocatalytic reaction $A + B \rightarrow 2A$ in which species A catalyzes the production of more of itself.²³ Since the rate of increase in the concentration of A over time t (dA/dt) is proportional to A , the solution to this differential rate equation (DRE) dictates that A exponentially increases over time. The population of species A is thus auto-amplified due to positive feedback – A begets more A . Such amplification (**Figure 3b**) is observed in many other nonlinear systems in everyday life, including the feedback that occurs when a microphone is placed too close to a speaker, compounding interest (“it takes money to make money”), ripening fruit, and social and telecommunications networks growing exponentially because bigger networks have more value (people want to be friends with people who have a lot of friends).

WHY EXTREME NONLINEARITY?

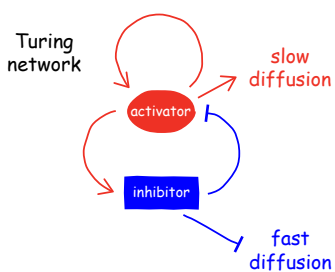
(a) SPECTRAL CONVERSION



(b) AMPLIFICATION



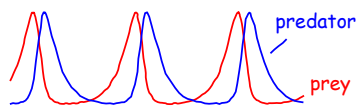
(c) REGULATING COMPLEX BEHAVIOR



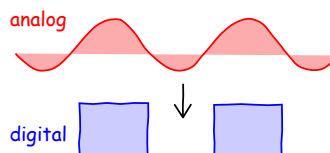
(d) PATTERNING



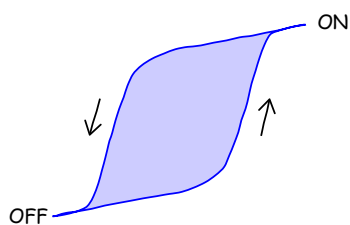
(e) OSCILLATION



(f) THRESHOLDING



(g) MEMORY



(h) MODELING COMPLEX SYSTEMS

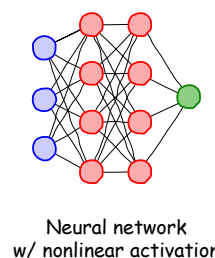


Figure 3. Utility and advantages of highly nonlinear systems. (e) adapted from Torii et al.²⁴

The greatest utility of nonlinearity is that it enables the encoding of complex behavior, which is valuable because life is rarely simple and linear. Nonlinear interactions in nature are often encoded as positive or negative feedback loops that stimulate or inhibit a process, respectively. In developmental biology, it has been hypothesized that autocatalytic reaction-diffusion networks and nonlinear gene regulation networks use such feedback to pattern organisms,²⁴ e.g. theoretical Turing patterns (**Figure 3c**),²⁵⁻²⁷ spots/stripes (**Figure 3d**),^{28, 29} and the segmentation of vertebrae and exoskeletons.^{30, 31} These nonlinear networks can also evolve dynamically in time to explain Circadian rhythms and the oscillation of predator and prey populations (e.g., the Lotka-Volterra model³², **Figure 3e**).²³ In principle, nonlinear systems can be designed to mimic biology and convert homogeneous systems into complex patterns that vary over time and space. Already, electronics and optics can be designed to leverage the nonlinear interactions of components to produce amplifiers that can turn analog signals into digital ones (**Figure 3f**).³³ Such amplification motifs can be combined in complex circuits to build oscillators, bistable switches, and memory elements (**Figure 3g**).³⁴ In optics, nonlinearities are observed not only in parametric nonlinear optical materials,²² but also in saturable absorbers that are used to turn continuous wave excitation into pulsed radiation (passive mode-locking).³⁵ Nonlinear changes in refractive indices also lead to lensing and self-focusing.³⁶ In machine learning, nonlinear activation functions built into neural networks allow them to model and predict complex, high-dimensional behavior (**Figure 3h**).³⁷ Thus, the question is not whether nonlinearity is useful, but whether the nonlinearity of ANPs can be harnessed in ways similar to the applications listed above.

Mystery #3: Why would you want nonlinearity on the nanoscale?

Reducing the dimensions of nonlinear materials to the nanometer scale has several key benefits.^{22, 36} Nanoscale materials have size- and shape-dependent properties due to confinement effects and their high surface-area-to-volume ratios.³⁸ Nanostructures can confine and enhance electromagnetic fields, leading to strong light-matter interactions that may further enhance nonlinear processes or increase their efficiency.³⁹ The optical properties of nanomaterials can be precisely tuned by controlling their size, shape, and composition, enabling optimization of nonlinear responses for specific applications. For colloidal nanoparticles, such as ANPs, their dispersibility enables applications such as biological labeling, which require materials to be suspended in solution, and they facilitate low-cost solution-phase fabrication for technological applications. Nanoscale dimensions allow nonlinear materials to be densely integrated into devices that match the length scales of current and future device fabrication nodes. The small size and solution processability of nanomaterials allow them to be combined into complex composites that have emergent properties that are not linear combinations of their components.^{40, 41} By leveraging these nanoscale advantages, researchers can create more efficient and compact nonlinear optical devices, access new nonlinear phenomena, and expand the applications of nonlinear optics in fields ranging from telecommunications to biomedicine.

3. The Mythical Origins of PA in Nanoparticles

Many myths about PA arise due to the lack of understanding of its origins and assumptions connecting it to other nonlinear materials, as we discuss below:

Myth #1: PA occurs through (1) a parametric nonlinear optical process or (2) delocalized excitonic states.

PA is sometimes mistaken for a parametric nonlinear optical process such as second harmonic generation (SHG) or sum frequency generation (SFG) (Figure 4a) or for a nonparametric process in which multiple photons are absorbed simultaneously (Figure 4b). Unlike these processes, PA is a step-wise non-parametric process most commonly observed in the ladder-like $4f^N$ excited states of trivalent lanthanide ions (Figure 4c).⁴ Due to the shielding of the $4f$ valence orbitals by filled $5s$ and $5p$ orbitals, these excited states are highly localized, unlike the excitons in semiconductor quantum dots (QDs, Figure 4b). This localization benefits ANPs by giving them high environmental stability and long excited-state lifetimes. Although QDs can also exhibit multiphoton emission, the fact that upconversion in ANPs and other upconverting nanoparticles (UCNPs) occurs through real, long-lived states rather than virtual states means that upconversion efficiencies are at least six orders of magnitude greater than the multiphoton emission from QDs or parametric nonlinear optical processes like SFG.⁴²

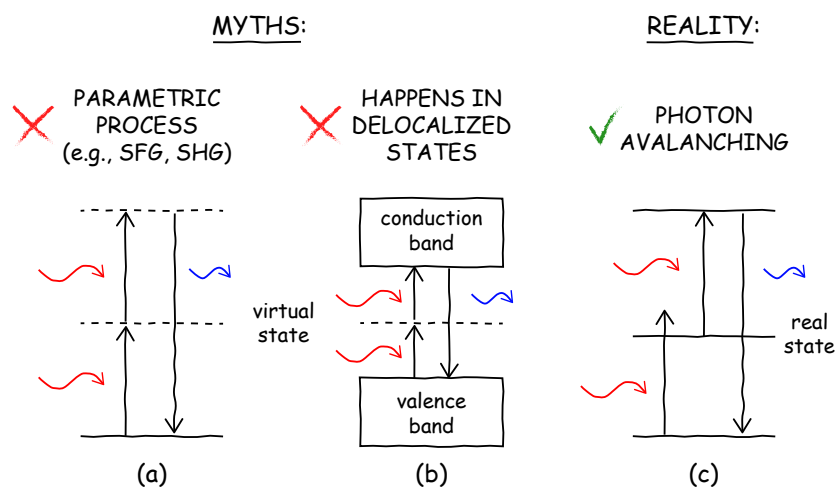


Figure 4. Origins of photon avalanching. Photon avalanche does not occur through a parametric process (a), virtual states, or via delocalized states in semiconductors (b). PA occurs through a step-wise process in the real, localized states of lanthanide ions. Energy level diagrams show the absorption and radiative relaxation (black vertical arrows), photon absorption (red wavy arrows), and upconverted emission (blue wavy arrows).

Myth #2: ANPs must have incredibly short emission wavelengths and low quantum yields if they involve 30+ photons.

In multiphoton absorption or SHG, the conservation of energy results in an emission wavelength of $\lambda_{em} \simeq \lambda_{ex}/N$, where λ_{ex} is the excitation wavelength (**Figure 5a**). Thus, a common misconception is that an ANP with a typical $N \sim 30$ would have incredibly short wavelength emission, e.g., 35 nm for a Tm^{3+} -doped ANP with $\lambda_{ex}=1064$ nm. In reality, such ANPs emit at 800 nm or visible wavelengths (**Figure 5b**) despite their large nonlinearity of 30. This modest anti-Stokes shift and decoupling of λ_{em} from N is beneficial for applications because extreme UV emission would preclude many technological and biological imaging applications. The small anti-Stokes shifts also simplify optics, particularly the materials and the spectral ranges over which they must perform.

A related misconception is that ANPs should have very low quantum yields if they involve 30+ photons. At typical avalanching threshold powers, a 30-photon absorption process or 30th harmonic generation would have exceedingly low efficiency due to the requirement that 30 photons interact simultaneously. Although it is impractical to directly measure the absolute quantum yield of ANPs due to their high nonlinearities and power requirements, calculations have indicated that ANPs reach theoretical quantum yields as high as $\sim 40\%$ at avalanching powers. These high theoretical efficiencies indicate that ANP nonlinearities of 30 do not actually imply the involvement of 30 photons, especially because the theoretical maximum of a 30-photon process would be 3.33%.

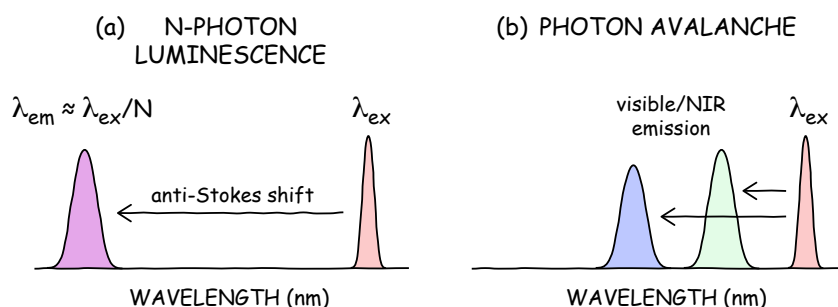


Figure 5. PA does not require large anti-Stokes shifts. High-order (N) multi-photon processes (a) typically result in large anti-Stokes shifts in which the emission wavelength $\lambda_{em} \simeq \lambda_{ex}/N$. In photon avalanching (b), however, λ_{em} is less coupled to λ_{ex} , resulting in small anti-Stokes shifts and visible or NIR emission.

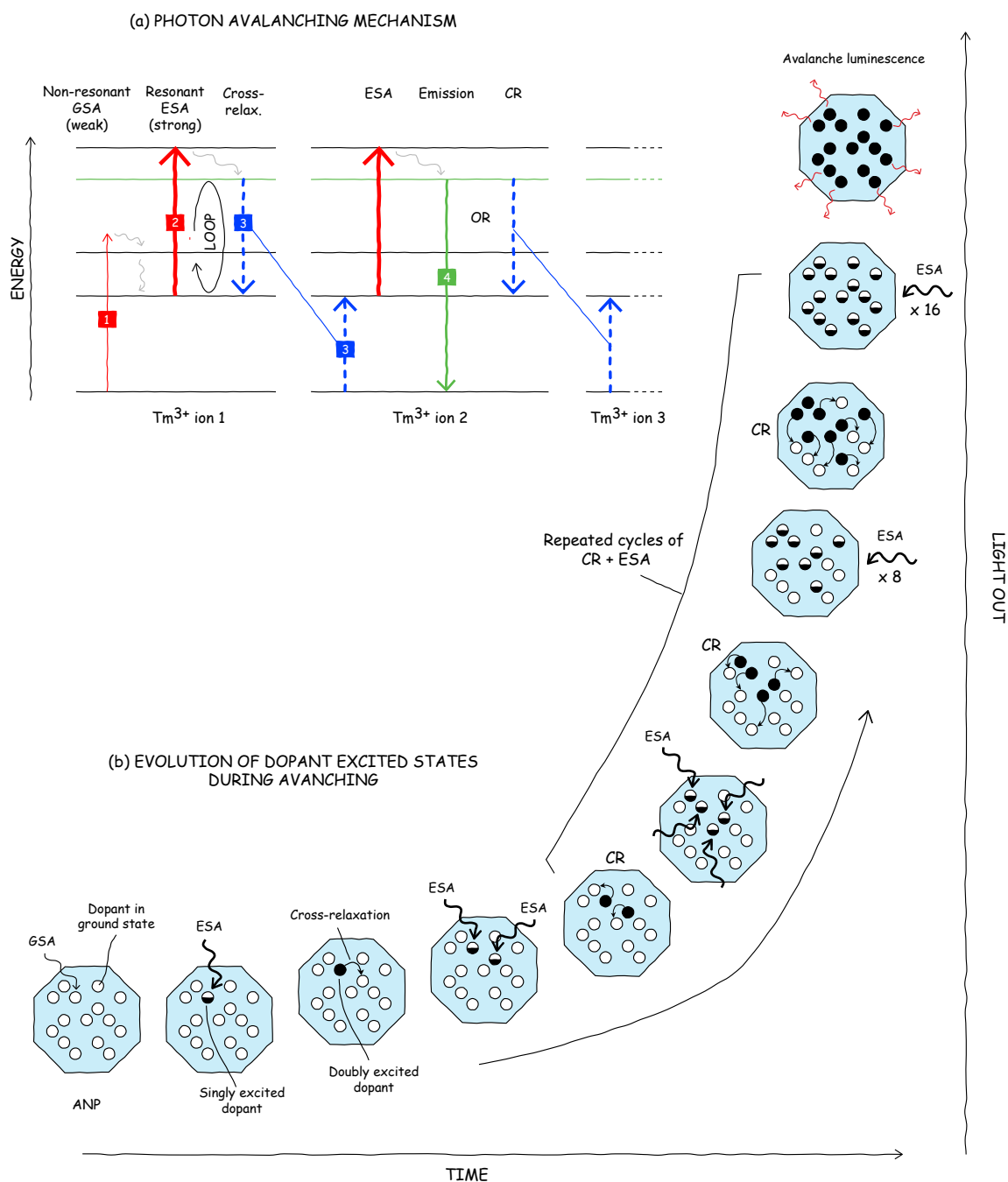


Figure 6. Mechanism of photon avalanching in lanthanide ions, shown for thulium (III). (a) Transitions between $4f^N$ manifolds (horizontal lines) include absorption (red arrows), cross-relaxation energy transfer (CR, blue dashed arrows), photon emission (green arrows), and multi-phonon relaxation (gray wavy arrows). (b) Step-by-step illustration of the evolution of dopant excited states during avalanching. Hollow, half-filled, and black-filled circles represent dopant ions in their ground, singly excited, and doubly excited states. Upconverted luminescence occurs via radiative transitions from the double doubly excited state.

Mystery #4: Why are photon avalanches so bad, they are good?

Highly nonlinear (“good”) PA requires three key components: (1) non-resonant or “bad” ground state absorption, (2) resonant excited state absorption, and (3) cross-relaxation energy transfer (**Figure 6a**).^{5, 12} Below, we discuss how these features combine to realize the mechanism of PA. The pathway begins with a non-resonant ground state absorption (GSA) transition to an intermediate state (Step 1 in Figure 6a), which is slow due to the need for the assistance of a phonon. This inauspicious beginning leads to the question of how any emission is observed if such little light is absorbed. The answer partially lies in the fact that PA materials also must have a resonant excited state absorption step (ESA, Step 2) that originates from an intermediate level populated by the initial GSA step. However, one may ask how substantial ESA can be when the inefficient GSA step is a bottleneck in any serial GSA+ESA upconversion process.

A critical feature of PA is an energy transfer (ET) cross-relaxation step (CR, Step 3) in which a doubly excited dopant ion (e.g., Tm^{3+} ion 1 in Figure 6a) donates part of its energy to a neighboring ion in its ground state (Tm^{3+} ion 2), producing two ions in their intermediate state. Due to the resonant ESA, these two singly excited ions can both undergo rapid ESA to their doubly excited states and then cross-relax with their neighbors again to result in four singly excited ions. This ESA + CR “energy loop”⁴³ can cycle repeatedly, in principle doubling the population of the intermediate level with every iteration (**Figure 6b**). This positive feedback loop, which exponentially amplifies the emission intensity over time, is the engine that gives rise to the extreme nonlinearity of PA.

Myth #3: Photon avalanches are avalanches of photons.

Now that we know the mechanism of PA, we can fully unravel why PA is not an avalanche of photons. While PA has a positive feedback loop of ESA + CR, photon emission is not a part of this loop. The emitted photons are not the same wavelength as the photons absorbed during ESA, so there is no feedback between photon emission and photon absorption. Instead, these emitted photons are side products that are output rarely and just happen to be enhanced by the increased population of the emitting level (e.g., Step 4 in Figure 6a).

The reason why PA emission exhibits high nonlinearity, even though it is not a key component of the feedback loop, is that the emitting level is fed by ESA from the intermediate level, which is the critical hub of the ESA+CR feedback loop. The heavy population of the intermediate level during this loop induces more ESA and CR, which in turn further populates the intermediate level. Thus, *PA is really an avalanche in the population of this intermediate excited state* (Figure 1), i.e., excited ions beget more excited ions, with the occasional emission of a photon on the side. Another way to think about PA is that the absorption of incident light leads to more absorption (ESA) due to the increased population of the absorbing intermediate species. Whether you think of PA as a population avalanche or an absorption avalanche, unraveling this myth is not just a semantic exercise. Identifying the actual nonlinear process and its engaged

energy levels is key to being able to manipulate and enhance the properties of ANPs, as we discuss below.

Myth #4: ANPs output more light than they receive.

A related myth is that the giant nonlinearity of PA allows ANPs to amplify photon emission such that the power of their emission is higher than the power of light incident upon them (**Figure 7a**). This, of course, would violate the laws of thermodynamics. In reality, ANPs and other PA materials do not even come close to exceeding the theoretical limits for such external quantum efficiency (EQE). Ln^{3+} ions, with their parity-forbidden $4f \rightarrow 4f$ optical transitions and practical limits on doping levels, absorb an almost insignificant fraction of the photons incident upon a nanoparticle. In order to reach 100% EQE (or even 50% EQE, the theoretical maximum for a two-photon process), each lanthanide ion would have to emit many photons for each absorbed photon just to make up for all of the incident photons that are not absorbed.

If the emission of ANPs increases nonlinearly, one might expect that the light output would eventually exceed the input power, but this would never happen for several reasons. First, the nonlinear increase of absorption and emission does not occur indefinitely. Absorbing ANP states become depleted with a sufficiently high excitation flux, slowing absorption and decreasing N .

Even if absorption did not saturate, the total PA emission power can never exceed the absorbed photon power because PA is an avalanche of absorption. The emission increases nonlinearly precisely *because* the absorption explodes nonlinearly. As shown in **Figure 6b**, each excited ion is generated by the absorption of a different photon. When eight singly excited ions undergo ESA and CR to produce eight more singly excited ions, an additional eight photons are required – there is no free lunch.

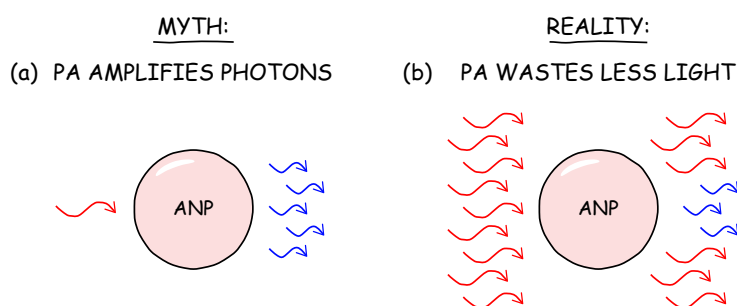


Figure 7. Photon avalanches do not amplify the number of photons incident upon them, as depicted in (a). Compared to pre-avalanching conditions, ANPs under avalanching conditions (b) dramatically absorb more pump photons due to the nonlinear amplification of intermediate excited state populations during avalanching.

Finally, it is important to reiterate that when we discuss the nonlinear increase of ESA and luminescence near avalanching threshold powers, the initial values from which we calculate the increase in these rates are not the excitation power but rather the exceedingly low rates of ESA and emission at sub-threshold powers. By amplifying absorption, PA enables ANPs to waste less of the vast number of photons that would normally transmit untouched through the ANP (**Figure 7b**). Thus, an underappreciated reality of ANPs is that they do not amplify photons or create them out of thin air – instead, the ANPs better utilize the incident photons that are not absorbed under non-avalanching conditions.

Myth #5: You can improve PA by enhancing ground state absorption.

In the PA mechanism described above, weak GSA (Step 1 in Figure 6a) is the bottleneck under sub-threshold pump powers, so it might seem reasonable to assume that more nonlinear PA or lower PA thresholds could be achieved by making the GSA step more resonant (e.g., by using excitation with a second laser or by using a sensitizing species). However, doing so would simply convert the system into a conventional two-step, GSA+ESA upconversion pathway in which strong GSA populates the intermediate level, followed by strong ESA from that level. While this system may indeed be brighter than the equivalent ANP at low powers, the nonlinearity would collapse, approaching $N \sim 2$. This reduced N highlights the fact that the extreme nonlinearity of ANPs is a direct consequence of the terrible GSA in the PA mechanism. The emission of ANPs is virtually non-existent at low, sub-threshold P_{ex} because the non-resonant GSA cannot populate the intermediate level before ions relax to their ground state. Only at threshold powers is the intermediate state population high enough to initiate the PA that allows the ANPs to emit appreciable amounts of light. Since the nonlinearity of the optical response describes the relative increase of the emission between different excitation powers, high N is only possible with low emission at low P_{ex} , which is realized through non-resonant GSA. As the GSA becomes more resonant, this low-power baseline is raised, reducing N . So, if one were interested in maximizing nonlinearity, one would want to decrease rather than increase the amount of GSA.

In fact, one of the three classic criteria for PA is that the ratio of ESA vs GSA cross sections (ESA/GSA) must be greater than or equal to 10^4 .^{42, 44} Thus, to maximize nonlinearity, one would want to make GSA as non-resonant as possible, which historically has been accomplished by cooling PA materials to cryogenic temperatures to minimize phonon-assisted absorption.

Mystery #5: How can you tell whether a material is really avalanching?

Mechanistically, we recognize PA as an energy-looping process that rapidly amplifies the number of excited states in ANPs, eliciting more ESA.⁴⁵ Yet, experimentally determining if a material follows this PA mechanism is less obvious. How does one determine whether a nanoparticle is avalanching, and how do we distinguish it from other possible mechanisms of photon upconversion, such as GSA+ESA or energy transfer upconversion (ETU)?⁴²

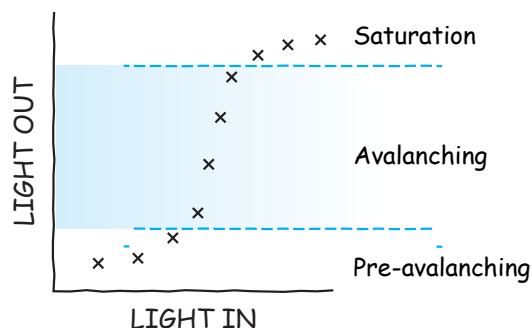
To meet the classic definition of PA, a material's optical response must meet three strict criteria: (1) a clear threshold, (2) $\text{ESA/GSA} > 10^4$, and (3) a slow-down of rise times. We discuss these three requirements below:

1. The optical response must exhibit a clear threshold. An avalanching system exhibits a threshold excitation power (P_{th}) above which the emission intensity of the material is amplified nonlinearly.^{45, 46} However, determining this threshold value, or even the presence of a threshold, is sometimes not trivial. To find the threshold, one typically measures the power-dependent profile of the PA emission intensity (**Figure 8a**), plotted as $\log(I_{em})$ vs $\log(P_{ex})$. While most multiphoton processes like ETU or two-photon emission exhibit linear traces (in log-log scaling) with slopes equal to N before they saturate at high powers, avalanching and energy-looping nanoparticles⁴³ exhibit "S-shaped" curves that can be divided into three regimes: pre-avalanching, avalanching, and saturation. The transition from the pre-avalanching to the avalanching regime marks the threshold of PA, P_{th} (**Figure 8b, left**). We can determine P_{th} by extrapolating linear fits of pre-avalanching and avalanching regimes in the $\log(I_{em})$ vs $\log(P_{ex})$ curves. The intersection of these lines indicates the P_{th} above which ANPs undergo PA.

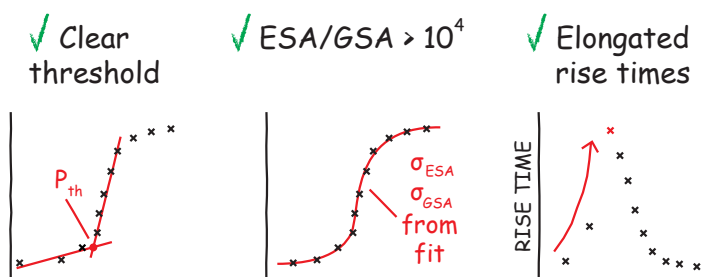
2. $\text{ESA/GSA} > 10^4$. As discussed previously, strong ESA and weak GSA are necessary conditions for PA, typically met in ANPs when $\text{ESA/GSA} > 10^4$. Due to the complexity of lanthanide photophysical networks,⁴⁷ the ESA and GSA cross-sections are impractical for most scientists to measure directly. Instead, one can fit the power-dependent emission profile of an ANP sample with a differential rate equation model (see Lee et al.,⁵ for example) in which the cross-sections for ESA and GSA are adjustable fit parameters (**Figure 8b, center**). One can then compare the ESA/GSA ratios of the rates or cross-sections (the literature is often ambiguous about which values to compare; cross-sections are often reported, but rates may be more relevant to PA).

3. Rise times become longer near the avalanching threshold. The most difficult criterion to meet, and the least reported, is that the luminescence rise times become dramatically longer near P_{th} – as high as hundreds of milliseconds compared to hundreds of microseconds for most lanthanide-doped nanoparticles.^{5, 15} Rise times are determined by acquiring the time-resolved luminescence of an ANP sample and measuring the time the luminescence takes to reach steady state after excitation begins (**Figure 8b, right**). For practical purposes, rise times are reported as the $t_{1/2}$ or $t_{90\%}$, the time taken to reach 50 or 90% of steady state intensity, respectively. We elaborate on the origins and misconceptions of this strange "slowing down" of rise times in Myth #6.

(a) MYSTERY: IS IT AVALANCHING?



(b) DEFINITELY AVALANCHING
(all 3 criteria required)



(c) PROBABLY AVALANCHING

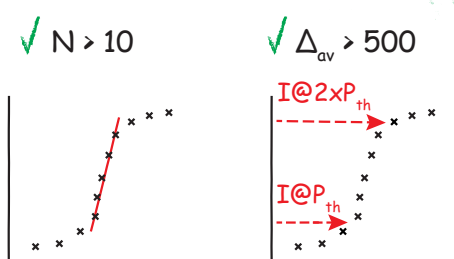


Figure 8. Experimental determination of avalanching. (a) Representative “S-shape” of the $\log(I_{em})$ vs. $\log(P_{ex})$ plot of PA materials, sub-divided into pre-avalanching, avalanching, and saturation regimes. (b) True PA materials exhibit clear threshold behavior (P_{th}), dominant excited state absorption ($ESA/GSA > 10^4$), and elongated rise times near P_{th} . (c) Materials with high nonlinearities ($N > 10$) and intensity amplification ratios ($\Delta_{av} > 500$) are generally regarded as photon avalanching.

Practical considerations when determining avalanching. While the three avalanching criteria listed above are specific, their evaluation can be clouded by real-world experimental constraints. One of the greatest issues with analyzing ANP intensity curves is that the luminescence in the pre-avalanching regime is extraordinarily dim and can go undetected if it is obscured by detector noise. Thus, long integration times should be used to minimize noise in the pre-avalanching region. Furthermore, the fitting of N from slopes of $\log(I_{em})$ vs $\log(P_{ex})$ curves is highly sensitive to the background intensity due to the log scaling. The background intensity must be carefully and objectively subtracted from the measured intensities. Also, to obtain a reliable N value, as many consecutive data points as possible should be used to fit $\log(I_{em})$ vs $\log(P_{ex})$ curves, and it is preferable to confirm the obtained N value from multiple independent measurements. Random fluctuations in emission intensity or pump power may accentuate changes between neighboring data points and lead to overestimating N at small sample sizes.

Alternate evidence for avalanching. A sample is definitely considered to be avalanching if it meets the three criteria delineated above (**Figure 8b**). However, finding the threshold, developing DRE models for unknown systems, and measuring rise times can be challenging and time-consuming. Recent publications have proposed more phenomenological metrics for avalanching that allow one to assess avalanching behavior based on how steeply its emission intensity scales with pump power. Although there is no strictly defined N value above which the material is said to be avalanching, a soft criterion for avalanching when $N > 10$ can be found and has historically been used in the ANP literature (**Figure 8c, left**).^{5, 10, 16}

To further corroborate PA in materials with $N > 10$, Lee et al.⁵ also define a Δ_{av} measure as a ratio of emission intensity when the pump intensity is increased from the threshold to twice the threshold value, $\Delta_{av} = I_{em}(2P_{th})/I_{em}(P_{th})$, where $I(P)$ is the emission intensity at pump intensity P (**Figure 8c, right**). The authors find Δ_{av} of 500 is a reasonable minimum to classify a system as avalanching, while the most nonlinear ANPs in their study ($N = 31.6$) exhibited Δ_{av} above 10^4 . Nanoparticles that exhibit both $N > 10$ and $\Delta_{av} > 500$ are highly likely to be classified as ANPs. The advantage of using N and Δ_{av} to roughly assess potential PA is that they can be determined quickly using just the power-dependent intensity profiles. Thus, they can be used to prescreen samples for more involved rise time and rate equation analysis (Figure 8b).

Finally, we note that some materials may exhibit most but not all of these criteria and be categorized as PA-like or energy-looping; however, it is essential to remember that regardless of the exact category, the excitation mechanism via ESA+CR differentiates PA from other upconversion processes. And regardless of its mechanism, the nonlinearity of a material ultimately determines its utility.

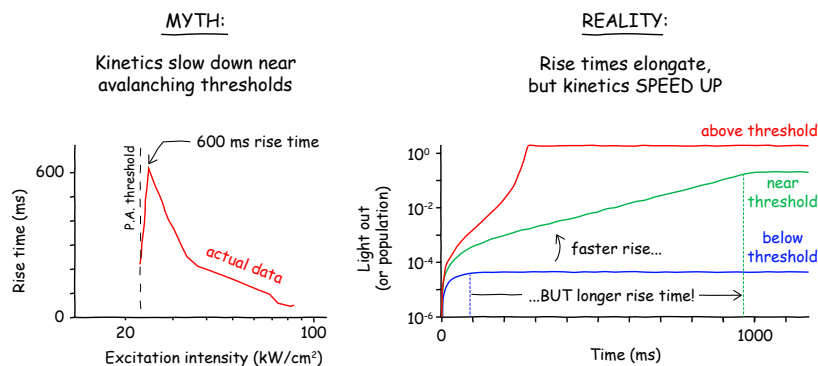


Figure 9. Photophysical kinetics do not slow down near PA thresholds. (a) Elongation of PA luminescence rise times for $\text{Tm}^{3+}:\text{NaYF}_4$ ANPs. Adapted from Lee et al.⁵ (b) Time-resolved luminescence traces below, near, and above PA thresholds, showing faster kinetics in parallel with longer rise times. Adapted from simulations by Skripka et al.¹⁶

Myth #6: Photophysical kinetics slow down near avalanching thresholds

The unusual mechanism of PA leads to some truly head-scratching and seemingly contradictory photophysics, most notably the oft-repeated belief that PA kinetics “slow down” near avalanching thresholds. It is true that the PA luminescence rise times lengthen dramatically in this regime (to 600 ms for Tm^{3+} -doped ANPs,⁵ shown in **Figure 9a**). However, it does not necessarily follow that the photophysical kinetics *slow down*. In fact, this is one of the greatest myths of ANPs.

To understand the origins of misconception, we must dive deeper into why rise times increase. In a normal UCNP, rise times tend to be relatively long (100 μs – 10 ms, comparable to luminescence decay lifetimes) due to the multi-step upconversion process. Ions must establish sufficient intermediate state populations before they can be excited again to the emitting levels. This population build-up can only occur so fast given the forbidden transitions of lanthanide ions.

How do dynamics get even slower for ANPs? *They don't*. In fact, the rate at which ANP luminescence rises actually gets *faster* as the pump power is increased near the avalanching threshold (**Figure 9b**). The PA time traces in Figure 9b, simulated for $\text{Nd}^{3+}:\text{KPb}_2\text{Cl}_5$ ANPs,¹⁶ show that the population of the intermediate $^4I_{11/2}$ excited state of Nd^{3+} rises faster over time as the power is increased from sub-threshold pump powers to above the avalanching threshold. Despite these faster kinetics, the rise times (indicated by the dashed vertical lines in Figure 9b) still get longer near the threshold.

To unravel this ball of contradictions, one can visualize dopant ions as buckets that hold water, where the water represents energy. In a conventional two-level fluorophore, the bucket size is roughly fixed. For a given flow rate (i.e., excitation power), a smaller bucket would mean a shorter filling time (i.e., rise time).

The trick to understanding the contradiction of ANPs is that their buckets are not fixed size! In our analogy, filling the buckets with water makes them increase in volume faster than the flow rate can catch up with it, leading to longer and longer filling times. The same thing happens for ANPs – every time a singly excited ion absorbs a photon (as in Figure 6b), the ESA+CR energy looping cycle produces two singly excited ions that can each absorb photons. This increased capacity to absorb photons increases the population at which the excited states will stabilize in their steady state (the plateau in the curves in Figure 6b). Since PA is an avalanche of absorption, the population of absorbing species and the capacity of the ANPs to absorb photons increase nonlinearly over time. As a result, the rise time elongates significantly near the avalanching threshold because this population ceiling rises faster than the system can approach it, even with increased kinetics.

4. Applications

Mystery #6: What are ANPs good for?

Now that we know ANPs work, how can their unique photophysics be exploited? The initial and killer application of ANPs has been their use as probes for imaging below the diffraction limit of the excitation radiation (**Figure 10a**), as we discuss in more detail in Myths #7 and #8.^{5, 6, 11, 48} The giant nonlinearities of ANPs enable standard scanning confocal microscopes to essentially perform N -photon microscopy (with $N > 26$) and resolve features as fine as 33 nm.^{5, 19} The less intuitive photoswitching properties of ANPs allow them to be localized using stochastic localization microscopy with localization accuracies less than 1 Å.⁶ In the future, the <100 nm emission point spread functions afforded by the nonlinear response of ANPs may be exploited in lithography⁴⁹ and 3D printing to create structures with unprecedented resolutions at depth (**Figure 10b**),⁵⁰ pending the demonstration of ANPs with highly nonlinear emission in the UV region.

The extreme nonlinearity of these nanocrystals also makes them exquisitely sensitive to external perturbations, which is beneficial in detecting minute changes in temperature,^{7, 51} pressure,⁸ or chemical environment (**Figure 10cde**). For example, Bednarkiewicz and coworkers have explored the distance-dependent quenching of ANP luminescence by small-molecule quenchers for molecular rulers or biological assays.^{52, 53} However, the sensitivity of ANPs is a double-edged sword. The effects of unaccounted phenomena, e.g., a slight temperature change when sensing pressure, are nonlinearly amplified, disrupting the delicate balance of PA and introducing artifacts into measurements. Thus, although sensing applications are likely to benefit from the unique properties of ANPs, a deeper and broader understanding of PA processes is needed to reliably extract measured quantities.

The ability of ANPs to toggle between their non-luminescent and luminescent states, either through persistent photoswitching⁶ or through dynamic bistability,⁹ inspires their use as optical switches, memory, analog-to-digital converters, or tiny signal integrators for reservoir computing¹⁰ and photonic neural networks³⁷ (see **Figure 10fgh**, and Mystery #9).^{9, 10} As research into ANPs is still in its infancy, more novel applications will surely be developed as we continue to develop new ANP materials and increase our understanding of their properties.

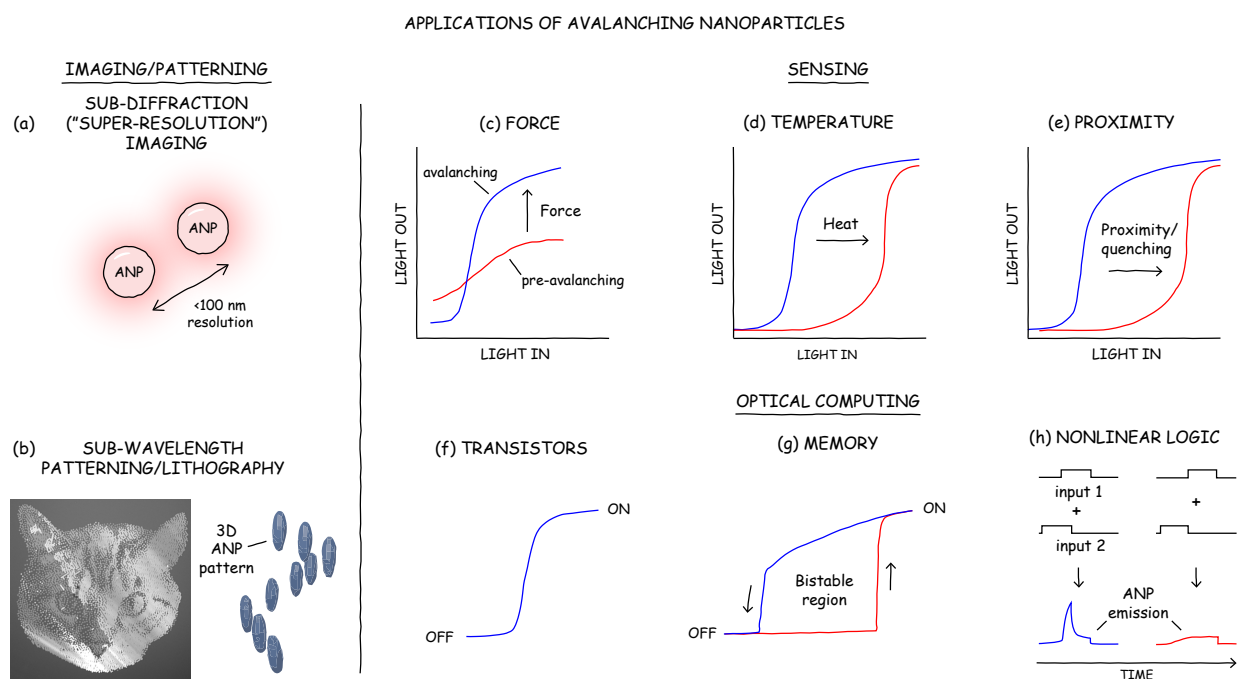


Figure 10. ANP applications in imaging (a), patterning and lithography (b); sensors for force (c), temperature (d), proximity to quenching molecules (e); and components for optical computing, including transistors (f), memory (g), and nonlinear logic (h). (b) Adapted from Pan et al.⁴⁹ and Lee et al.⁶ (c) Adapted from Fardian-Melamed et al.⁸ (d) Adapted from Szalkowski et al.⁵¹ (e) Adapted from Majak et al.⁵³ (g) Adapted from Skripka et al.⁹ (h) Adapted from Bednarkiewicz et al.¹⁰

Myth #7: Confocal imaging with PA enables breaking of the resolution limit

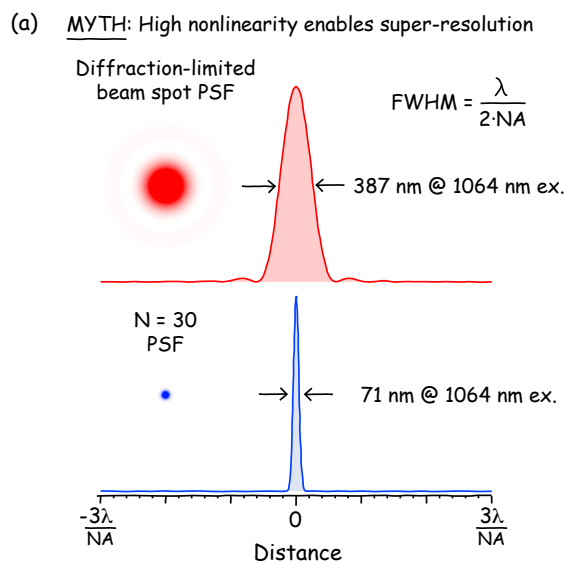
The signature application for ANPs has been imaging below the diffraction limit of the pump excitation wavelength, achieving resolutions as low as 33 nm^{11, 18} using only a simple scanning confocal microscope. The simplicity of such photon avalanche single-beam super-resolution imaging (PASSI¹⁵) is that it does not require the complex optical setups of super-resolution techniques such as Stimulated Emission Depletion (STED) or complex post-processing of the data required for techniques such as Photoactivated Localization Microscopy (PALM⁵⁴), Stochastic Optical Reconstruction Microscopy (STORM⁵⁵), or structured illumination microscopy (SIM). In contrast, PASSI¹⁵ involves scanning a diffraction-limited excitation spot across a field of

ANPs and detecting the emission only when an ANP is almost directly in the center of the beam spot (**Figure 11**).

A common myth about ANPs is that their non-linearity gives them the ability to be imaged below their theoretical resolution limit, i.e., with “super-resolution” (as PASSI acronym erroneously suggests). In conventional imaging with linear emitters, the diffraction-limited resolution can be considered as the full-width at half maximum (FWHM) of the point spread function (PSF) of the excitation beam spot, i.e., an Airy disk. According to the Abbe resolution equation, the FWHM is $\frac{\lambda}{2 NA}$, which for an excitation wavelength λ of 1064 nm and a numerical aperture (NA) of 1.4 equals 387 nm (**Figure 11a, top**).

Sub-diffraction imaging with ANPs leverages the giant nonlinearity of PA along with the fact that a diffraction-limited excitation spot is more intense in its center than on its edges. For an ANP with $N = 30$, a point on the Airy disk with half the maximum excitation intensity theoretically would excite 0.5^{30} or 1 *billionth* of the emission intensity at the center of the beam spot (accounting for typical saturation of PA in ANPs, realistically this contrast is more like $1/10,000^{\text{th}}$ of the maximum intensity). Only a slight decrease in intensity to 97.7% of the maximum pump irradiation would result in half the maximum emission, meaning that the FWHM of the emission of an ANP will be dramatically smaller than for a linear emitter. For $\lambda = 1064$ nm and $NA = 1.4$, the FWHM resolution would be 71 nm (**Figure 11a, bottom**) compared to the 387 nm diffraction limit. With ANP nonlinearities now reported to exceed 100, such ANPs have been imaged with resolutions as low as 33 nm, with theoretical limits smaller than 20 nm.

So why is it a myth that ANPs break the resolution limit? The misconception lies in the fact that ANPs do not break the resolution limit, but rather, they lower it. In fact, all multiphoton microscopy methods, even with N as low as 2, will result in finer resolution than single-photon microscopy. When the Abbe resolution equation is modified for nonlinear microscopy, the resolution is calculated to be $\frac{\lambda}{2 NA \sqrt{N}}$ (**Figure 11b**). Importantly, this equation describes the FWHM of the emission profile, such that two ANPs separated by this distance can be resolved. Thus, PASSI acquires images at the actual optical resolution, i.e., the FWHM of the emission PSF, but this resolution itself moves to smaller distances as N increases. This is not the same as super-resolution, like stochastic localization microscopy techniques (PALM, STORM) that localize individual features within the emission PSF. However, PASSI is not the only mode of sub-diffraction imaging available to ANPs, as we discuss in the next myth.



(b) REALITY: Resolution changes with nonlinearity

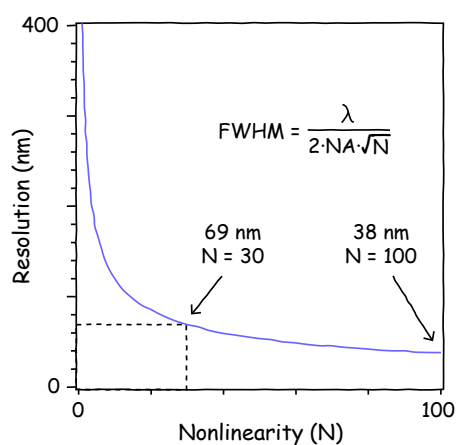


Figure 11. (a) Point spread functions (PSF) of a diffraction-limited beam spot Airy pattern (top) and the emission profile from an ANP with $N = 30$. (b) Resolution vs N , illustrating how PA confocal imaging occurs at actual resolution, rather than exceeding it. Dashed lines show resolution for $N = 30$. All FWHM and resolution values are shown for excitation at 1064 nm and $\text{NA} = 1.4$.

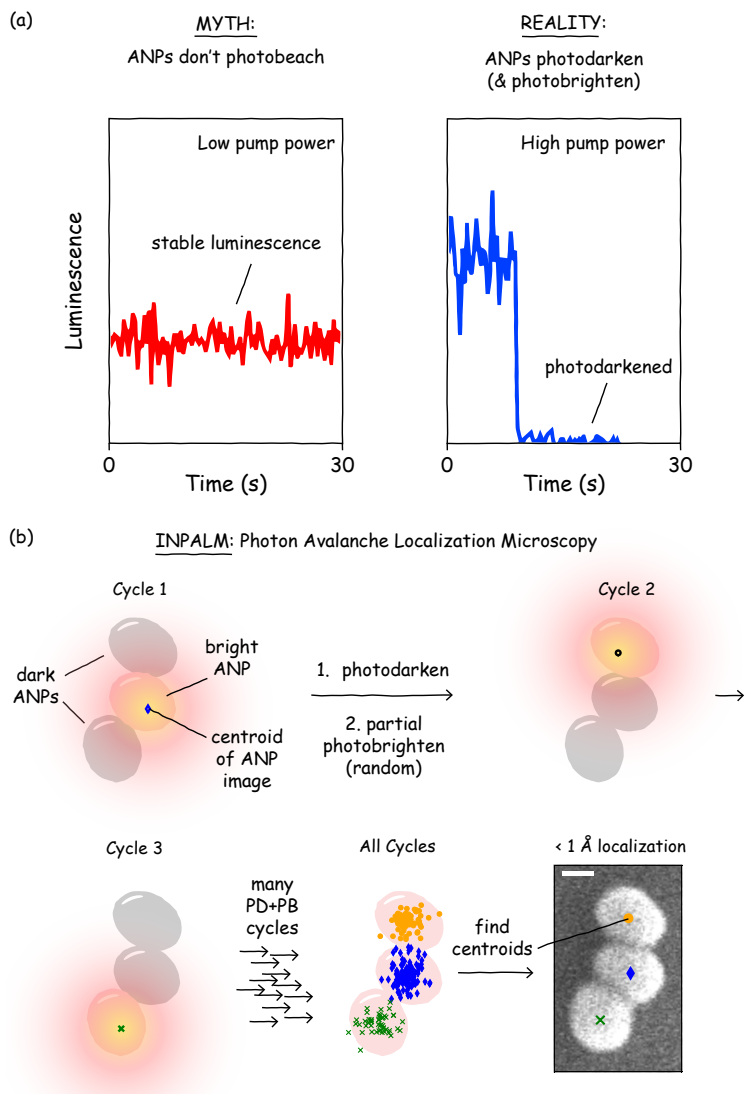


Figure 12. (a) ANPs photodarken under high-intensity excitation (several times the avalanching threshold power), unlike conventional upconverting nanoparticles, which are stable over hours of continuous high-power excitation. (b) The photobrightening (PB) and photodarkening (PD) of ANPs can be harnessed for sub-diffraction-limited localization microscopy (INPALM) with $< 1 \text{ \AA}$ localization accuracy. Scale bar for scanning electron microscopy overlay: 20 nm. Adapted from Lee et al.⁶

Myth #8: ANPs do not photobleach (which would be detrimental for high resolution imaging)

Lanthanide-doped UCNPs are renowned for their exceptional photostability,⁵⁶ making them valuable for single-particle imaging and long-term studies. Unlike organic dyes, which readily photobleach,^{54, 55} and unlike quantum dots, which blink intermittently,⁵⁷ conventional UCNPs like $\text{Yb}^{3+}/\text{Tm}^{3+}:\text{NaYF}_4$ emit at a constant intensity even under hours of continuous excitation at irradiances exceeding 10^6 W/cm^2 (**Figure 12a, left**).

Given their incredibly similar compositions, it would be logical to assume that ANPs have similar photostabilities to UCNPs. Surprisingly, this reasonable inference would be incorrect! When excited at high irradiances – several times the avalanching threshold power but still within typical pump powers used for UCNPs – ANPs like NaYF₄:8% Tm³⁺ abruptly photodarken⁶ (**Figure 12a, right**).

Such photodarkening would seem to make ANPs a poor choice for imaging, particularly when tracking single nanoparticles with confocal microscopy (PASSI). Fortunately, photodarkened ANPs can be subsequently restored to their previous “bright” state by exciting them with higher energy light (400-940 nm for Tm³⁺-doped ANPs excited at 1064 nm).⁶ At intermediate intensities, this photobrightening process is not complete, such that only a random subset of ANPs is returned to their bright state. Importantly, ANPs can be photobrightened and photodarkened over more than 1000 cycles – so many that the maximum number of cycles has not been established.

This ability to photodarken and stochastically photobrighten ANPs is reminiscent of stochastic localization microscopy methods like PALM⁵⁴ or STORM,⁵⁵ in which all of the organic dyes are bleached and then a subset is randomly activated. These techniques can image finer than the diffraction-limited resolution by activating a small enough fraction of emitters that are unlikely to have emitting neighbors within their emission PSF, thereby allowing localization of their single-molecule emission spots.

ANPs have been leveraged in a similar manner for super-resolution localization microscopy using a technique called indefinite NIR PA localization microscopy (INPALM⁶), whose step-by-step process is shown in **Figure 12b**. During INPALM imaging, an ensemble of nanoparticles is fully photodarkened by a high-powered excitation source, and then a small fraction of the ANPs is photobrightened by using an intermediate dose of a second laser. The centroids of the emission spots of those bright single ANPs are then localized, and the particles are subsequently photodarkened. A second set of ANPs is photobrightened and localized, and this process is repeated many times until each nanoparticle has a large set of localization coordinates. Finally, two-dimensional (2D) Gaussians are used to fit localization points for each ANP, generating a centroid and uncertainty for each ANP. Using INPALM, ANPs have been imaged with localization accuracies finer than 1 Å. Due to this accuracy, the centroids of 35 nm ANPs can be determined even when the nanocrystals are touching. INPALM has a major advantage over stochastic localization methods that use organic dyes, since ANPs can be cycled indefinitely without photobleaching like organic dyes. This is important because the localization accuracy is inversely proportional to the square root of the number of photons collected, suggesting that the accuracy of INPALM has no theoretical limit.

Thus, while ANPs do photodarken, their ability to recover their emission and be cycled indefinitely allows them to access a second mode of sub-diffraction imaging. And unlike PASSI, INPALM does in fact break the resolution limit.

Mystery #9: How do some ANPs live two parallel lives? Do they remember their past lives?

Nonlinear networks can exhibit memory, lag, or echo in their response to external inputs, often due to the different scaling laws of competing processes (see, for example, the lag between the predator and prey populations in Figure 3g). UCNP, made out of thousands of interacting Ln^{3+} ions,⁴⁷ are no exception, with ANPs elevating these phenomena to a new level.

Recently, we found that $\text{Nd}^{3+}:\text{KPb}_2\text{Cl}_5$ ANPs²¹ can live parallel lives: the same nanocrystal can appear dark (no luminescence) or bright (emitting light) under identical excitation wavelengths and pump powers.⁹ Their current state – dark or bright – is determined by the history of pump power, as if these ANPs can “remember” the preceding laser power and respond in one of the two ways. Such response is called optical bistability and is characterized by power-dependent luminescence hysteresis (Figure 10g). In $\text{Nd}^{3+}:\text{KPb}_2\text{Cl}_5$ ANPs, optical bistability arises from competition between two opposing forces: PA and phonon relaxation. Vibrational properties of the KPb_2Cl_5 host and low temperatures reduce phonon assistance to electronic transitions, like GSA, requiring higher powers to switch these ANPs on. However, once these ANPs do emit, a rapid population of excited states via energy looping can outcompete multiphonon relaxation (energy dissipation as heat), maintaining the bright state of ANPs even below the switch-on threshold. Think of it as riding a bike. At first, getting the bike moving takes a lot of effort because you have to push the pedals really hard. But once the bike is moving, the bike has inertia and keeps moving even after pedaling ceases. Of course, eventually the bike will stop.

Bistable ANPs eventually switch off but at lower laser powers than were required to switch them on. Since the photoluminescence in optically bistable ANPs vanishes without a laser pump, their memory is volatile. Observing luminescence hysteresis and being able to switch these ANPs from a dark to a bright state (see Myth #13) opens opportunities to use them as nanoscale switches and memories for optical computing.^{58, 59}

Classic $\text{Tm}^{3+}:\text{NaYF}_4$ ANPs can also remember, so to speak, their not-so-distant past. The population of the Tm^{3+} energy-looping intermediate state, which facilitates ESA, could be dynamically controlled by time-gating pump laser pulses.¹⁰ If two excitation pulses overlap in time, the intermediate state is populated, and ANPs emit light (**Figure 10h**). However, if the delay between pulses is longer than the lifetime of the intermediate state, the ANPs do not emit light. Such behavior resembles signal integration by biological synapses and could be used in optical reservoir computing. This type of computing, leveraged in machine learning, utilizes a non-linear system as a reservoir, just like Ln^{3+} -doped ANPs, to process information inputs without requiring system training (only the outputs need to be trained), accelerating computation and reducing costs.

5. Drawbacks of ANPs

Myth #10: ANPs are ready for prime time.

The ANP literature may seem that ANPs are ready to be integrated into applications, but there are a number of downsides to these unique materials – some that may be easy to overcome and some that may never be overcome. Areas in which ANPs still need to improve relative to other fluorophores include their low brightness and quantum yields and their moderately high-power requirements (kW/cm^2). The exquisite nonlinearity of ANPs makes them particularly sensitive to small fluctuations in their excitation powers or attenuation of the excitation due to scattering and refraction in their local environment. This sensitivity can make applications difficult to calibrate, especially when considering that ANPs can have slight variations in their brightness and avalanching thresholds due to slight differences in size,⁶⁰ composition, shell thickness,⁶¹ and even excitation beam profile.⁶⁰ Finally, the photodarkening of ANPs leveraged for super-resolution imaging can be problematic for applications that do not require photoswitching. Future research is required to ameliorate these drawbacks. However, some of these issues can already be addressed by existing technology. For example, the photodarkening of ANPs can be counteracted by subsequent photobrightening. And as we discuss below, some of the perceived drawbacks of ANPs are myths, while others further reveal hidden truths about the dark sides of ANPs.

Myth #11: You can change the color or excitation wavelength of ANPs by introducing different dopants into existing ANP systems.

Imaging, display, and sensing applications of ANP may require a library of probes with different emission or excitation wavelengths. Such spectral diversity is critical for cases in which multiple species are being tracked simultaneously, and spectral breadth is important, for example, for extending excitation wavelengths into NIR and SWIR windows in which photons have the lowest attenuation in highly scattering media such as tissue.⁶²⁻⁶⁴

ANPs are relatively new materials, so it is no surprise that they are only available in a handful of emission and excitation wavelengths. Because ANPs are strictly driven via ESA, the laser wavelength must be carefully tuned to maximize ESA and minimize GSA, as is the case of 1064 nm excitation for Tm^{3+} or Nd^{3+} and 852 nm for Pr^{3+} ions.^{15, 18, 43, 65} Deviating from these wavelengths eliminates PA or, at the very least, reduces the nonlinearities of ANPs. Due to these and other constraints, it is challenging to expand the library of the currently known avalanching systems (Tm^{3+} , Nd^{3+} , Yb/Pr^{3+}). Thus, there is a need to be able to modify the emission wavelengths of these existing ANPs.

MYTH: Long PA rise times preclude rapid imaging
REALITY: Edges of beam spot prime neighboring ANPs

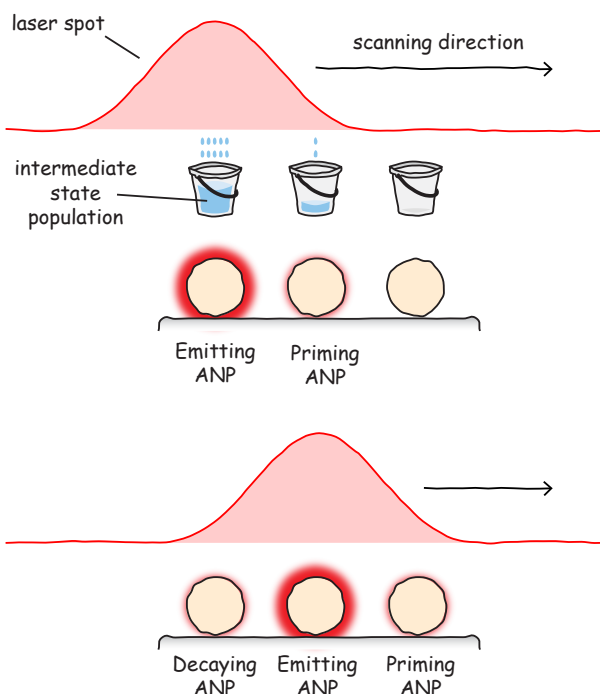


Figure 13. Although the long rise times of avalanching nanoparticles may appear to preclude rapid scanning for video-rate imaging, the actual rise times for ANPs directly under the excitation beam are shorter because they have been previously primed by excitation on the edges of the beam spot when the beam is focused on a nearby ANP.

To change the emission or excitation bands of Ln^{3+} -doped UCNPs, one typically mixes different sensitizing or emitting dopants and changes their concentrations.⁶⁶ Therefore, it might be reasonable to assume that one could introduce other dopants into known ANPs to induce them to emit at different wavelengths. However, these traditional methods for spectral tailoring do not readily translate to ANPs since adding even the tiniest amounts of co-dopants is often detrimental to PA.⁵³ Co-dopants act as energy sinks, depopulating excited states involved in light absorption or emission of photon avalanching Ln^{3+} ions. Due to the extreme nonlinearity of PA, such small perturbations can have outsized influence on the nonlinearity and intensity of homogeneously co-doped ANPs.

Fortunately, there is a workaround for introducing other ions in ANPs. To ensure that incompatible ions do not share the same space, one can synthesize Ln^{3+} -doped nanocrystal heterostructures with multiple layers, like layers of an onion, with each layer having unique dopants and a unique role.^{67, 68} In such core/shell UCNPs, a third dopant is incorporated in both

the core and the shell(s) as a bridge to migrate excitation energy, via resonant ET, from the light-absorbing ion to the light-emitting ion without them interacting directly.⁶⁹

This concept of energy migration has been successfully applied to several core/shell ANPs. The excitation energy, captured by the “PA engine” of Tm^{3+} ions (or the $\text{Yb}^{3+}/\text{Pr}^{3+}$ couple), migrates through a sublattice of Gd^{3+} or Yb^{3+} ions to excite non-PA ions like Eu^{3+} or Tb^{3+} , located in a different domain of the same nanocrystal.¹⁶⁻¹⁹ The same concept has been applied to excite external emitters¹⁶ such as CdS/CdSe/CdS quantum dot heterostructures.⁷⁰⁻⁷² Through energy migration, the giant nonlinearities of ANPs can be preserved and imprinted on the energy-accepting ions to emit nonlinearly at different colors.

Taking the long path of energy migration does come with a cost, including inadvertently increasing the avalanching threshold, reducing the nonlinearity, or reducing the emission intensity. Nonetheless, these first demonstrations show great promise in creating multicolor libraries of ANPs and transforming ordinarily linear emitters into highly nonlinear ones.

In addition to core/shell engineering, the same PA ions may have different emission colors when introduced in host materials with different properties. For example, orange PA emission was generated in low-phonon-energy $\text{Nd}^{3+}:\text{KPB}_2\text{Cl}_5$ ANPs,²¹ while blue emission was reported in tetragonal $\text{Tm}^{3+}:\text{LiYF}_4$ ANPs, which have different Ln^{3+} site symmetry to hexagonal $\text{Tm}^{3+}:\text{NaYF}_4$ ANPs.⁶⁰

Myth #13. The slow rise times of PA mean ANPs can't be used for video-rate imaging

One consequence of the slow rise times of ANPs is that they limit the scanning speed of raster-based imaging methods. An ANP with a rise time greater than half a second would require pixel dwell times at least that long just to be able to view the ANP at its maximum intensity. In fact, demonstrations of the two different modes of deeply subwavelength imaging (PASSI and INPALM) routinely used integration times and photobrightening/darkening times from 0.5 s⁵ to as long as 8 s.⁶ Is the resolution gain of PASSI or INPALM worth sacrificing imaging speed? For biologists studying live cells and the dynamic world inside them, the answer might be “no.” Spending 0.5 s or more on every pixel might mean missing out on important cellular events.

Several promising solutions to this problem have been proposed or demonstrated. The first relies on the fact that the laser beams have approximately Gaussian beam profiles with widths much larger than the size of individual ANPs. This means that the outer edges of the beam spot have non-zero intensities, resulting in the weak excitation of ANPs in that region. Because the power on the periphery is below the PA threshold, these ANPs barely emit, so they don't contribute to the signal of the ANPs being imaged in the center of the beam spot. But the excited state population of the ANPs on the edges of the beam is primed – they are pre-avalanching. In our previous analogy of filling buckets with water, the Gaussian laser beam is a shower head that sprays water over a wide radius. So, as we fill one bucket in the center and move to the next in line, the next one is already partially filled, such that it will take less time to top it off (**Figure 13**). Similarly, the edge of the laser beam primes the ANPs around the ones

currently being imaging, reducing rise times and drastically improving imaging speeds when the center of the beam moves over the primed ANPs.⁵

To further increase imaging speeds, we can use multiple lasers to create complex illumination patterns. We can imagine irradiation schemes where priming is done by a second, low-power laser either preceding the main beam or illuminating the entire sample. This second beam would prime next-in-line ANPs right to the avalanching threshold so that when our scanning beam comes around, ANPs emit without much delay. The potential of priming has been demonstrated in both Tm^{3+} ANPs (see Supplementary Information) and for $\text{KPb}_2\text{Cl}_5:\text{Nd}^{3+}$ ANPs that are optically bistable (Mystery #9).⁹ These bistable ANPs were primed by a wavelength resonant with their ESA below P_{th} and then exposed to a short pulse of a second beam – resonant with GSA. These initially dark, non-emitting ANPs underwent instability crossing and became bright, emitting even after the second laser was turned off. Such a fast and direct photoswitching of ANPs illustrates how Ln^{3+} ions, with their multiple excited states, enable various priming strategies.

A final approach that can be used in conjunction with the first two is splitting excitation beams into parallel focused beams. Such beam spot arrays can be quickly scanned across an entire sample. With the aid of CCDs for two-dimensional acquisition and photon localization to extract the positions of ANPs, Lee et al.⁶ demonstrated theoretically that such multi-spot imaging can image ANP-labeled areas of interest with resolutions of 80 nm using only 25 frames. At 0.6 s per frame, this scan would take 16 min.

With these advances and discoveries, slow rise times of PA do not prevent us from acquiring fast, possibly video-rate, high-resolution images with ANPs. We are not limited by the rise times of ANPs when raster scanning samples because our Gaussian beam primes nanocrystals in its vicinity, and implementing multi-beam irradiation may help reduce imaging times even further.

6. The future

Mystery #7: Where do ANPs go from here?

Surface engineering. If ANPs are not quite ready for widespread application, where does their near-term future lie? As suggested above, there are fundamental issues with ANPs that need to be addressed through basic research. For example, imaging applications – many of them in the biological realm – require a deeper understanding of how surface effects^{53, 61} influence the highly sensitive PA process, which may be quenched by ET to ligands and solvents. Super-resolution imaging and sensing in cells and tissue may require the development of new inorganic and polymeric coatings and ligands, particularly those with lower molecular weight, low vibration energies,⁷³ resistance to oxidative degradation,⁷⁴ and those that enable robust coupling with biological species like antibodies.⁷⁵ Increasing the absorption cross sections of ANPs without disrupting their ESA/GSA ratio may require the development of innovative approaches to

sensitize these transitions with dyes,⁷⁶⁻⁷⁸ transition metals, or by coupling the transitions strategically to plasmon modes.⁷⁹

Understanding photodarkening and photobrightening. Further research is also required to understand the origins of photodarkening (PD) and photobrightening (PB) of ANPs, which is not seen in conventional UCNPs. Although it has been proposed that PD and PB processes are related to the respective generation and annihilation of color centers in the NaYF₄ host matrix⁶ (following reported mechanisms in bulk materials⁸⁰), deeper investigations are needed to confirm or identify the actual defects and mechanism. For INPALM microscopy, such models may be used to learn how to speed up the PD/PB processes to increase scan rates and reduce laser powers, while increased mechanistic understanding may also provide a path to suppress PD for PASSI and sensing applications for which photobleaching is a nuisance. A critical roadblock for understanding the origins of PD/PB is our limited ability to visualize such defects directly. Progress in this area may require advances in electron microscopy, such as automation of low-dose and phase-contrast techniques,⁸¹ ultrasensitive detectors,⁸² tomography/pytochraphy,⁸³ and *in situ* methods, particularly those that couple with laser excitation.⁸⁴⁻⁸⁶ Advanced X-ray techniques such as X-ray absorption spectroscopy⁸⁷ (e.g., EXAFS) and pump-probe methods under free electron lasers⁸⁸ may also provide structural insight into the steady state or transient formation of defects. Scanning tunneling microscopy may provide the most direct insight into the location and electronic structure of defects in thin ANPs,⁸⁹ while techniques borrowed from the persistent luminescence nanomaterials community may elucidate thermodynamic properties and design rules for such defects.⁹⁰ Control experiments will be required to examine whether photodarkening and defects are a consequence of a specific synthetic method or host matrix, or if other preparations and materials have increased or suppressed photodarkening.

Implementing ANPs in the real world. Many of the proof-of-concept demonstrations or predictions for ANPs, such as sub-diffraction imaging and patterning,^{5,6} pressure sensing,⁸ UV disinfection,⁹¹ and optical computing,¹⁰ still need to be demonstrated for real-world applications. While there are a handful of examples of sub-wavelength imaging of ANPs of fixed cells,¹⁸ imaging and sensing with ANPs still need to be demonstrated on live cells to monitor physiologically relevant processes in a way that provides insight into current biological problems, with performance that matches or exceeds state-of-the-art techniques. And while the exquisite temperature sensitivity of ANPs has been theoretically predicted, sub-wavelength PA nanothermometry has yet to be demonstrated experimentally, even though such nanometer-resolution thermometry has been demonstrated for single UCNPs,⁹²⁻⁹⁴ even in live cells and organelles.⁹⁵

Finally, the greatest challenge and opportunity for ANPs is developing new applications for nanoscale PA that have yet to be envisioned. These may include anti-counterfeiting labels,⁹⁶ since high-order nonlinear processes are more challenging to invert than linear or low-order processes.⁹⁷ The complexity of PA responses, including their power-dependent lifetimes and emission intensities, convoluted with the wide encoding space of heterostructures, make them difficult to reverse engineer and useful for physical unclonable functions,⁹⁸ such as those resistant to quantum computing attacks.⁹⁹

Optical networks and computing. The development of ANPs is an important milestone for our long-term vision of building highly integrated, nanoscale optical circuits. Amplifiers are key components in the electronic circuits and biological reaction networks that we seek to mimic with ANPs, particularly since the positive feedback of PA provides the nonlinear behavior that enables complex outputs.⁴⁷ Optical nonlinearities are generally sought-after in photonic integrated circuits, e.g., powering activation functions for deep neural networks³⁷ or performing analog-to-digital signal conversion (as in Figure 3fh). Hence, ANPs, with their giant nonlinearities and small sizes that can facilitate very-large-scale integration, provide a pathway for general-purpose optical computing, with the ANPs acting as components in larger optical logic circuits. For example, memory could be implemented with bistable ANPs, while the addition of upconverting materials and waveguides or energy migration relays would establish interconnects. Notably, the relatively minor anti-Stokes shift between excitation and emission lines of ANPs facilitates signal cascading over many interconnected nanocrystals, which would be impossible in materials whose nonlinearities derive from parametric processes or multi-photon absorption.

Alternatively, single ANPs could themselves be engineered as self-contained optical circuits that reproduce the behavior of canonical electronic and biochemical networks. To complete this vision, however, optical motifs for other major components besides positive feedback loops must be developed. For example, optical Turing patterns (Figure 3f) would require optical motifs that can mimic the amplification, inhibition, and diffusion processes in the network diagram shown in Figure 3e.²⁴ In ANPs, this could be accomplished via processes such as PA, cross-relaxation ET, and resonant energy migration, respectively. These elements would be encoded as doped domains within core-shell ANP heterostructures (as in migrating PA motifs^{16, 18}), in barcode nanorods,^{100, 101} or more complex branched heterostructures.¹⁰² In practice, however, numerous components that do not have equivalents in the UCNP world still remain to be developed, and integrating existing components can face challenges such as alignment of energy levels. Ultimately, the development of such libraries of optical motifs will allow lanthanide-doped nanostructures to serve as circuit boards on which such motifs can be modularly connected via iterative chemical synthesis^{103, 104} to build complex nanoscale optical circuits.

Complex ANPs through machine learning and automated discovery. If the future of ANPs is complex heterostructures that serve as optical breadboards, how will these intricate ANP compositions, with their large number of parameters, be optimized? Computational modeling will be important for identifying the best compositions for motifs and their optimal assembly into larger networks. While simple rate equation models can be adapted for core-shell materials with simple geometries (e.g. concentric),¹⁰⁵ kinetic Monte Carlo (kMC) models allow for the modeling of complex heterostructures with arbitrary geometries and dopant distributions.^{47, 68, 106} A major challenge for kMC modeling, however, is their computational expense – one simulation of a large, multi-shell nanoparticle of the diameter required to encode a complex network (>30 nm) can require weeks or months of computational time even

on high performance computing clusters. The large number of simulations required to optimize such structures would make kMC screening impractical.

To overcome this challenge, ANP heterostructures in the future can be optimized by machine learning (ML) models trained on simulation data, as was recently demonstrated for UCNP heterostructures.⁶⁸ Active learning approaches¹⁰⁷⁻¹⁰⁹ such as Bayesian Optimization can be used to iteratively and efficiently search through compositional space spanned by as many as seven dimensions, such as those that describe the concentrations and dimensions of triply doped core-shell UCNPs.⁶⁸ However, for the even higher number of parameters required for the most complex heterostructures, deep learning models such as convolutional neural networks may be more efficient, although they may require large simulation datasets for training. Such ML-guided approaches may also aid other areas of ANP research, such as searching for ligands that enhance ANP emission.^{73, 110} Because the use of ML to accelerate ANP and UCNP research is in its infancy,^{68, 111-119} we may look towards ML-guided approaches^{108, 109} for accelerating the discovery of other nanomaterials¹²⁰ like quantum dots and perovskites.^{107, 121, 122} Such data-driven techniques can also guide experimental campaigns, particularly when used in conjunction with high-throughput automated workflows.^{66, 123, 124} Future approaches may leverage ML models that combine multiple data streams – experimental, theoretical, and literature-based data – to autonomously guide robotic synthesis¹²⁵⁻¹²⁷ and optical characterization of the most promising ANP candidates and those that help refine existing understanding.

7. Conclusions

In this focus article, we have dispelled some of the largest misconceptions and most common questions about photon avalanching nanoparticles that we hear as we share our ANP research. Some of these questions are as fundamental as what goes in an ANP and why its nonlinearity is useful, while common myths center around the origins of PA and how PA can be enhanced. We have explored the truly puzzling contradictions of PA – that its rise times get longer as its kinetics get faster, and that ANP imaging can sometimes break the resolution limit without achieving super-resolution. Understanding the true nature of ANPs, including the limitations described here, may allow researchers to design brighter, more stable ANPs with a variety of colors and faster responses – helping these materials to meld their unique nonlinearity properties with real-world demands.

Perhaps the greatest mystery of ANPs is what new properties and applications will emerge in the future. Similar to the repeated branching illustrated in pictorial representations of PA, ANPs have continually and consistently revealed novel behavior and intriguing use-cases at every turn. To illustrate how ANPs are the gift that keeps on giving, we conclude this focus article by describing our journey in ANP research and how it continually branched and fed back upon itself. In 2014, in search of UCNPs that could be excited through brain, we and our collaborators computationally predicted and experimentally verified energy looping in Tm³⁺-doped

nanoparticles.⁴³ While not sufficiently nonlinear to be classified as ANPs, these “ELNPs” inspired our long-term vision of nonlinear optical networks.⁴⁷ This vision led to the development of highly Tm³⁺-doped ANPs that met the strict criteria for PA outlined in Figure 8b⁵ and the demonstration of sub-wavelength imaging (PASSI, as predicted by Bednarkiewicz et al¹⁵). During this ANP research, our collaborators coincidentally observed photodarkening in the same nanoparticles, leading to the development of INPALM.⁶ In ostensibly separate research, our efforts to make brighter UCNPs with low-phonon-energy hosts²¹ led to the observation of PA-driven intrinsic optical bistability in Nd³⁺-doped KPb₂Cl₅ ANPs, which exhibit nonlinearities greater than 100.⁹

What are the lessons to be learned from our journey? First, computational predictions were essential since conventional UCNP thinking would not have suggested such strange and contradictory materials. Second, in every step of this journey, each small advance has led to a chain reaction of further advances that have revealed new insight into lanthanide-doped avalanching nanomaterials. Finally, many of our discoveries were serendipitous, defying the idealized scientific myth of intentionality. Synergistic collaborations, cutting-edge techniques, and open minds were critical for amplifying seemingly minor observations into grand hypotheses and scientific outcomes. We hope that disproving the myths presented here and unraveling the mysteries of ANPs will similarly amplify research in ANPs and their applications and continue the chain reaction of novel discoveries for these peculiar and nonlinear nanoparticles.

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